

High Performance Regulators for PCs

Nch FET Ultra LDO Controllers for PC Chipsets





BD3504FVM,BD3500FVM,BD3501FVM,BD3502FVM

No.10030EAT29

Description

The BD3500/01/02/04FVM is an ultra-low dropout linear regulator controller for chipset that can achieve ultra-low voltage input to ultra-low voltage output. By using N-MOSFET for external power transistor, the controller can be used at ultra-low I/O voltage difference up to voltage difference generated by ON resistance. In addition, because best suited power transistor can be chosen in accord with the output current, downsizing and cost reduction of the set can be achieved. Because by reducing the I/O voltage difference, large current output is achieved and conversion loss can be reduced, switching power supply can be replaced. BD3500/01/02/04FVM does not need any choke coil, diode for rectification and power transistor which are required for switching power supply, total cost of the set can be reduced and compact size can be achieved for the set. Using external resistors, optional output from 0.65V to 2.5V can be set. In addition, since voltage output start-up time can be adjusted by using the NRCS terminal, it is possible to flexibly meet the power supply sequence of the set.

Features

- 1) Reduced rush current by NRCS
- 2) Built-in driver for external Nch h transistor
- 3) Adoption of MSOP8 package: 2.9 x 4.0 x 0.9 (mm)
- 4) Built-in timer latch short protection circuit
- 5) Built-in low input maloperation prevention circuit
- 6) Output voltage variable type
- 7) Built-in overheat protection circuit

Applications

Mobile PC, desktop PC, digital home appliances

Line up matrix

| io ap maanx | | | | |
|---------------------------------|-----------------------|-----------------------|-----------------------|--|
| Parameter | BD3500FVM | BD3501FVM | BD3502FVM | BD3504FVM |
| Output Voltage | 1.8V (Fix) | 1.5V (Fix) | 1.2V (Fix) | Variable(0.65~2.5V) |
| NRCS | 0 | 0 | 0 | 0 |
| (Soft start) | (Independent Setting) | (Independent Setting) | (Independent Setting) | (Same Timer Latch) |
| Timer latch short | 0 | 0 | 0 | 0 |
| protection circuit | (Independent Setting) | (Independent Setting) | (Independent Setting) | (Same NRCS) |
| VIN UVLO | Hysterisis | Hysterisis | Hysterisis | Detected at start-up only (set by external resistor) |
| External FET GATE Drive Current | +1/-3mA | +1/-3mA | +1/-3mA | +3/-3mA |

● Absolute maximum ratings (Ta=25°C)

@BD3500/01/02FVM

| Parameter | Symbol | Ratings | Unit |
|------------------------------|--------|----------------------|------|
| Input Voltage | VCC | 7 *1 | V |
| Drain Voltage (VIN) | VIN | 7 | V |
| Enable Input Voltage | Ven | 7 | V |
| Power Dissipation | Pd | 437.5 * ² | mW |
| Operating Temperature Range | Topr | -10~+100 | °C |
| Storage Temperature Range | Tstg | -55~+150 | °C |
| Maximum Junction Temperature | Tjmax | +150 | °C |

©BD3504FVM

| Parameter | Symbol | Ratings | Unit |
|------------------------------|--------|----------------------|------|
| Supply Voltage | VCC | 7 * ³ | V |
| Drain Voltage | VD | 7 | V |
| Enable Input Voltage | Ven | 7 | V |
| Power dissipation | Pd | 437.5 * ⁴ | mW |
| Operating temperature range | Topr | -10~+100 | °C |
| Storage temperature range | Tstg | -55 ~ +150 | °C |
| Maximum Junction Temperature | Tjmax | +150 | °C |

Recommended operating conditions

©BD3500/01/02FVM

| Parameter | Symbol | Rat | Unit | |
|----------------------------|--------|---------|------|-------|
| | Symbol | MIN | MAX | Offic |
| Supply Voltage | VCC | 4.5 | 5.5 | V |
| Drain Voltage(VIN) | VIN | Vox1.15 | 5.5 | V |
| Enable Input Voltage | Ven | -0.3 | 5.5 | V |
| Capacitor on NRCS Terminal | CNRCS | 0.001 | 1 | μF |
| Capacitor on SCP Terminal | CSCP | 0.001 | 1 | μF |

[★] No radiation-resistant design is adopted for the present product.

⊚BD3504FVM

| Cumbal | Rat | Unit | |
|--------|--------------------|---|--|
| Symbol | MIN | MAX | Offic |
| VCC | 4.5 | 5.5 | V |
| VD | 0.65 | 5.5 | V |
| Ven | -0.3 | 5.5 | V |
| CNRCS | 0.001 | 1 | μF |
| VOUT | 0.65 | 2.5 | V |
| | VD Ven CNRCS | Symbol MIN VCC 4.5 VD 0.65 Ven -0.3 CNRCS 0.001 | VCC 4.5 5.5 VD 0.65 5.5 Ven -0.3 5.5 CNRCS 0.001 1 |

[★] No radiation-resistant design is adopted for the present product.

^{*1} However, not exceeding Pd.
*2 Pd derating at 3.5mW/°C for temperature above Ta=25°C

^{*3} However, not exceeding Pd.
*4 Pd derating at 3.5mW/°C for temperature above Ta=25°C

● Electrical characteristics (unless otherwise noted, Ta=25°C VCC=5V Vin=3.3V Ven=3V)

©BD3500FVM/BD3501FVM/BD3502FVM

| Parameter | Symbol | | andard Value | | Unit | Condition |
|---------------------------------|---------------------|---------|--------------|---------|----------|--|
| | C y c | MIN | TYP | MAX | O | 33.13.13.1 |
| Bias Current | ICC | - | 8.0 | 1.6 | mA | |
| Shut Down Mode Current | IST | - | 0 | 10 | μΑ | Ven=0V |
| Output Voltage 1 (BD3500FVM) | Vo1 | 1.782 | 1.800 | 1.818 | V | Io=50mA |
| Output Voltage 1 (BD3501FVM) | Vo1 | 1.485 | 1.500 | 1.515 | V | Io=50mA |
| Output Voltage 1 (BD3502FVM) | Vo1 | 1.188 | 1.200 | 1.212 | V | Io=50mA |
| Output Voltage 2 (BD3500FVM) | Vo2 | 1.746 | 1.800 | 1.854 | V | Vcc=4.5V to 5.5V ,lo=0 to 3A Ta=-10°C to 100°C(%) |
| Output Voltage 2 (BD3501FVM) | Vo2 | 1.455 | 1.500 | 1.545 | V | Vcc=4.5V to 5.5V ,lo=0 to 3A Ta=-10°C to 100°C(%) |
| Output Voltage 2 (BD3502FVM) | Vo2 | 1.164 | 1.200 | 1.236 | V | Vcc=4.5V to 5.5V ,lo=0 to 3A Ta=-10°C to 100°C(%) |
| Line Regulation | Reg.I | - | 0.1 | 0.5 | %/V | VCC=4.5V to 5.5V |
| Load Regulation | Reg.L | - | 0.5 | 10 | mV | Io=0 to 3A |
| Enable] | | | | | | |
| High Level Enable Input Voltage | Enhi | 2 | - | Vcc | V | |
| Low Level Enable Input Voltage | Enlow | -0.3 | 1 | 8.0 | V | |
| Enable Pin Input Current | len | - | 7 | 10 | μΑ | Ven=3V |
| NRCS] | | | | | | |
| NRCS Charge Current | Inrcs | 14 | 20 | 26 | μΑ | Vnrcs=0.5V,VCC=4.5V to 5.5V Ta=-10°C to 100°C (※) |
| NRCS Standby Voltage | Vnrcs | - | 0 | 50 | mV | Ven=0V |
| Voltage Feed Back] | | | | | | |
| VFB Input Bias Current | IFB | - | 0.7 | 1.2 | mA | Ven=3V |
| VFB Standby Current | FBSTB | 150 | - | - | mA | Ven=0V,VFB=1V |
| Output MOSFET Driver] | | | | | | |
| MOSFET Driver Source Current | IGSO | 0.5 | 1 | 1.5 | mA | VFB=Vo-0.1V,G=Vo+1V |
| MOSFET Driver Sink Current | IGSI | 2 | 3 | 4 | mA | VFB=Vo+0.1V,G=Vo+1V |
| UVLO] | | | | | | |
| VCC UVLO | VccUVLO | 4.2 | 4.35 | 4.5 | V | Vcc:Sweep up |
| VCC UVLO Hysteresis | Vcchys | 100 | 160 | 220 | mV | Vcc:Sweep down |
| VIN UVLO | VINUVLO | Vo×1.05 | Vo×1.1 | Vo×1.15 | V | VIN:Sweep up |
| VIN UVLO Hysteresis | VINhys | 100 | 160 | 220 | mV | VIN:Sweep down |
| SCP] | | | | | | |
| SCP Charge Current | Iscpch | 14 | 20 | 26 | μA | VSCP=0.5V,VCC=4.5V to 5.5V Ta=-10°C to 100°C (※) |
| SCP Discharge Current | IscpDi | 0.5 | ı | - | mA | VSCP=0.5V |
| SCP Threshold Voltage | Vscpth | 1.2 | 1.3 | 1.4 | V | |
| Short Detect Voltage | Vscp | Vox0.6 | Vo×0.7 | Vo×0.8 | V | |
| Short Detect voltage | V COP | VOX0.0 | 10110.1 | 10/10.0 | • | |

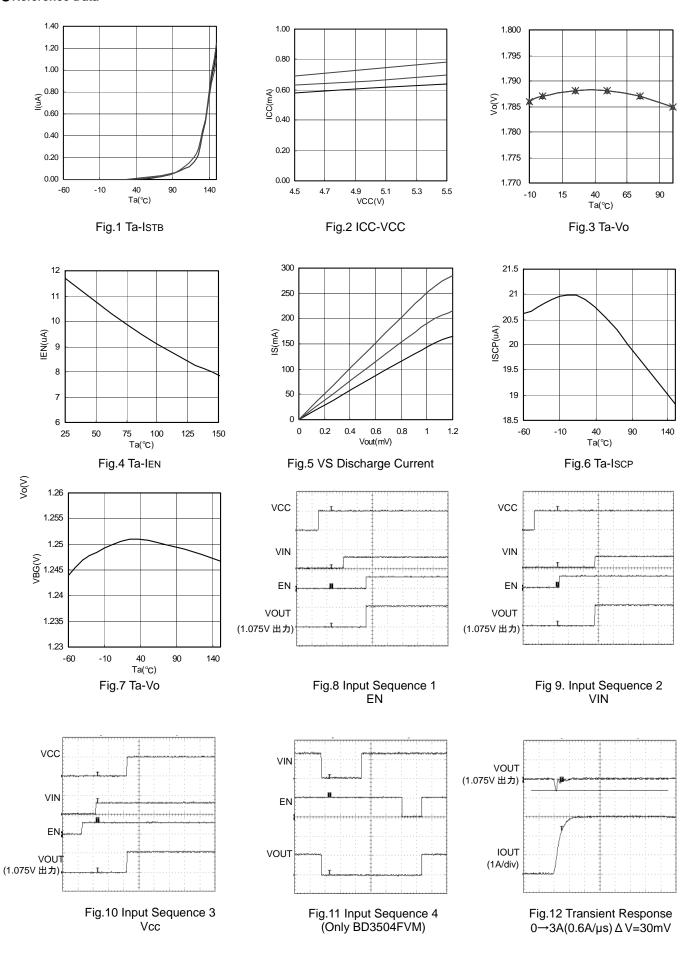
(※) Design Guarantee

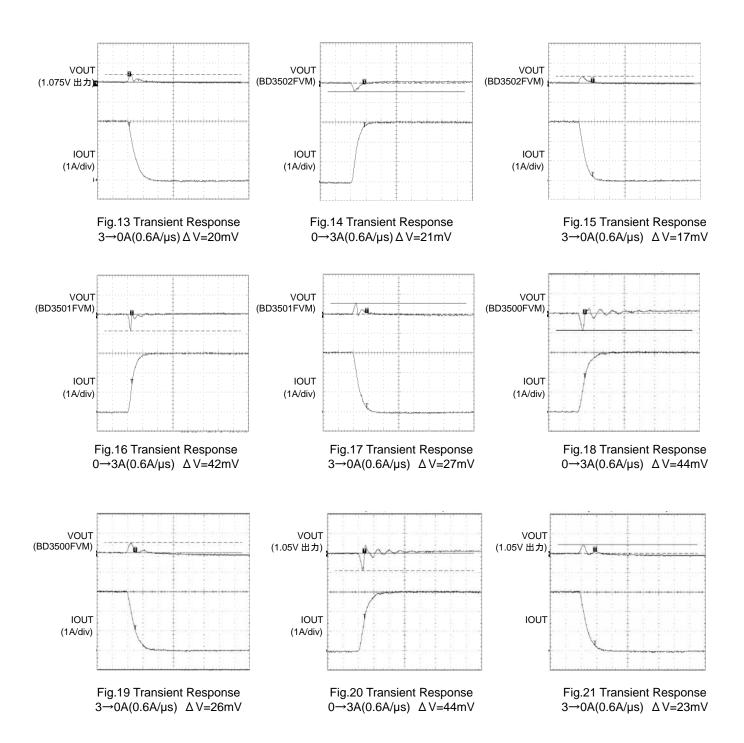
●Electrical characteristics (unless otherwise noted, Ta=25°C VCC=5V VIN=3.3V Ven=3V. R1=R1'=∞Ω, R2=R2'=0Ω) ◎BD3504FVM

| Doromotor | Symbol | St | andard Val | ue | Unit | Condition |
|---------------------------------|---------|--------|------------|--------|-------|--|
| Parameter | Symbol | MIN | TYP | MAX | UTIIL | Condition |
| Bias Current | ICC | - | 0.85 | 1.7 | mA | |
| Shut Down Mode Current | IST | - | 0 | 10 | μΑ | Ven=0V |
| Feed Back Voltage 1 | VFB1 | 0.643 | 0.650 | 0.657 | V | Io=50mA |
| Feed Back Voltage 2 | VFB2 | 0.630 | 0.650 | 0.670 | V | Vcc=4.5V to 5.5V , Ta=-10°C to 100°C(%) |
| Output Voltage | Vo | - | 1.20 | ı | V | R1=R1'=3.9kΩ, R2=R2'=3.3KΩ |
| Line Regulation | Reg.I | - | 0.1 | 0.5 | %/V | VCC=4.5V to 5.5V |
| Load Regulation | Reg.L | - | 0.5 | 10 | mV | Io=0 to 3A |
| [Enable] | | | | | • | |
| High Level Enable Input Voltage | Enhi | 2 | - | Vcc | V | |
| Low Level Enable Input Voltage | Enlow | -0.3 | - | 0.8 | V | |
| Enable pin Input Current | len | - | 7 | 10 | μΑ | Ven=3V |
| [Voltage Feed Back] | • | | • | | • | |
| VFB Input Bias Current | IFB | - | 80 | - | nA | |
| [Source Voltage] | 1 | | II. | | | |
| VS Input Bias Current | ISBIAS | - | 1.2 | 2.4 | mA | |
| VS Standby Current | ISSTB | 150 | - | - | mA | VS=1V Ven=0V |
| [Output MOSFET Driver] | 1 | | II. | | | |
| MOSFET Driver Source Current | IGSO | 2 | 3 | 4 | mA | VFB=0.6V,VGATE=2.5V |
| MOSFET Driver Sink Current | IGSI | 2 | 3 | 4 | mA | VFB=0.7V,VGATE=2.5V |
| [UVLO] | 1 | | II. | | | |
| VCC UVLO | VccUVLO | 4.20 | 4.35 | 4.50 | V | Vcc:Sweep up |
| VCC UVLO Hysterisis | Vcchys | 100 | 160 | 220 | mV | Vcc:Sweep down |
| VD UVLO | VDUVLO | Vo×0.6 | Vo×0.7 | Vo×0.8 | V | VD:Sweep up |
| [Drain Voltage Sensing] | II. | l | II. | | | |
| VD Input bias Current | lvd | - | 0 | - | nA | |
| [NRCS/SCP] | | Ti- | II. | | 1 | 1 |
| NRCS Charge Current | Inrcs | 14 | 20 | 26 | μA | VNRCS=0.5V |
| SCP Charge Current | Iscpch | 14 | 20 | 26 | μΑ | VNRCS=0.5V |
| SCP Discharge Current | IscpDi | 0.3 | - | - | mA | VNRCS=0.5V |
| SCP Threshold Voltage | Vscp | 1.2 | 1.3 | 1.4 | V | |
| Short Detect Voltage | Voscp | Vo×0.3 | Vo×0.35 | Vo×0.4 | V | |
| NRCS Stand-by Voltage | VSTB | - | - | 50 | mV | |

^(※) Design Guarantee

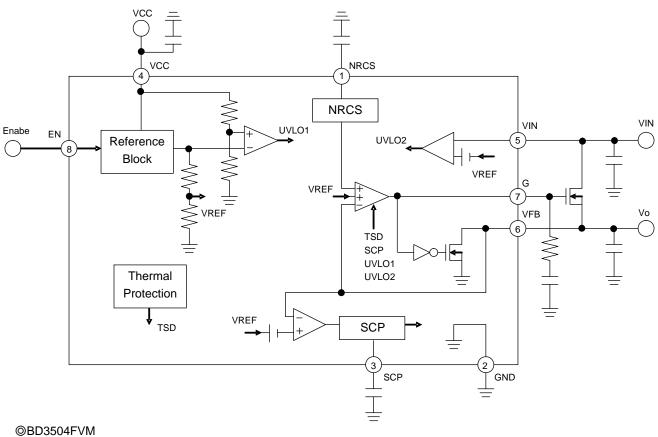
● Reference Data

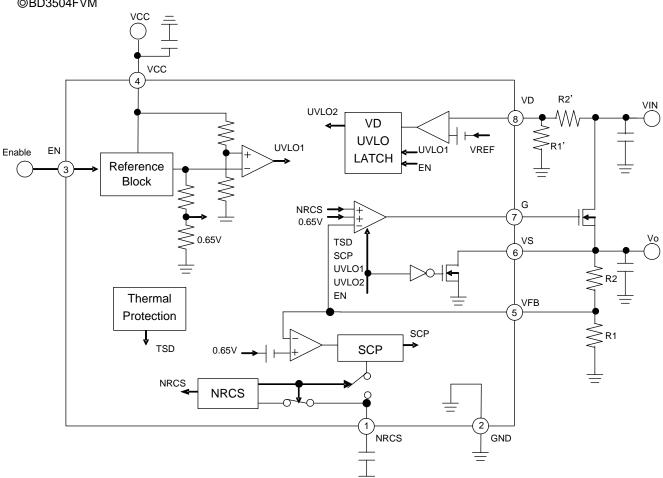




●Block Diagram

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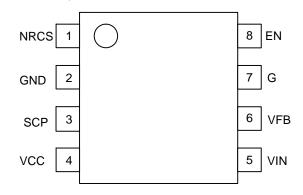




●Pin Configration and Pin Function

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OPin Configration

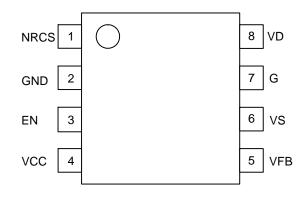


OPin Function

| ┙. | ui | lotion | |
|----|------------|-------------|--|
| | Pin No. | Pin Name | PIN FUNCTION |
| | 1 | NRCS | (Non Rush Current on Start up) time setup |
| | 2 | GND | Ground pin |
| | 3 | SCP | Timer latch setup for Short Circuit Protection |
| | 4 | VCC | Power Source |
| | 5 | VIN | Drain Voltage Sense |
| | 6 | VFB | Output Voltage Feedback |
| | 7 | G | MOSFET Driver Output |
| | 8 | EN | Enable |

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OPin Configration



OPin Function

| Pin No. | Pin Name | PIN FUNCTION |
|------------|-------------|---|
| 1 | NRCS | NRCS (Non Rush Current on Start up) time setup. Timer latch setup for Short Circuit Protection operating time set up Pin. |
| 2 | GND | Ground Pin |
| 3 | EN | Enable Pin |
| 4 | VCC | Power Source |
| 5 | VFB | Output Voltage Feedback |
| 6 | VS | Source Voltage Pin |
| 7 | G | MOSFET Driver Output |
| 8 | VD | Drain Voltage Sense |

●Pin Function Descriptions

VCC

BD3500/01/02/04FVM has an independent power input pin for an internal circuit operation of IC. This is used for bias of IC internal circuit and external N-MOSFET. The voltage used of VCC terminal is 5.0V and maximum current is 1.7 mA. It is recommended to connect a bypass capacitor of 0.1 μ F or so to VCC pin.

EN

With an input of 2.0 volts or higher, the EN terminal turns to "High" level and VOUT is outputted. At 0.8V or lower, it detects "Low" level and VOUT is turned OFF and simultaneously, the discharge circuit inside the VS terminal is activated and lowers output voltage (150 mA (Min) when VFB//VS=1V and VEN=0V).

VIN(BD3500/01/02FVM)

The VIN terminal is a drain voltage detection terminal of external N-MOSFET. In the event that the VIN terminal is lower than 1.1 times the output set voltage, output is turned OFF to prevent low-input maloperation.

VD(BD3504FVM only)

The VD terminal is a drain voltage detection terminal of external N-MOSFET. In the event that drain voltage (VIN) is low, output voltage is turned OFF to prevent low-input maloperation. The reset voltage (VDUVLO) of drain voltage low-input maloperation prevention circuit is determined by the following equation:

VDUVLO=VFB × 0.7 ×
$$\left(\frac{R1'+R2}{R1'}\right)$$

In the event that the maloperation prevention set resistance at the time of low-input drain voltage is set to a resistance value same as output voltage set resistor (R1 = R1', R2 = R2'), low-input maloperation prevention (UVLO) is reset when drain voltage (VIN) reaches 70% of the output voltage. UVLO detects only at the startup of the EN terminal.

VFB(BD3504FVM only)

The VFB terminal is a terminal to decide output voltage and is determined by the following equation:

$$VOUT=VFB \times \left(\frac{R1'+R2}{R1'}\right)$$

VFB is controlled to achieve 0.65 V (typ.).

NRCS terminal

he NRCS terminal is a constant current output terminal, and operates as

- Soft-Start ... during start-up
- •SCP-Delay ... after start-up (BD3504FVM only).

How to set Soft-Start of NRCS terminal

The output voltage startup time (TNRCS) is determined by the time when the NRCS terminal reaches VFB (0.65V). During start-up, the NRCS terminal serves as a constant current source (INRCS) of 20 μ A (Typ.) output, and charges capacitor (CNRCS) externally connected. By changing over to internal reference voltage (0.65V) when the NRCS terminal reaches 0.65V, output voltage (VOUT) is fixed.

How to set NRCS terminal short protection Delay (BD3504FVM only)

BD3504FVM has short protection (SCP) activated when output voltage becomes VOUT x 0.35 (typ.) or lower. The time when short protection is activated until latching takes place (TSCP) is determined by the following equation:

When short protection is activated, the NRCS terminal provides 20 µA (typ.) constant current output (Iscp), and charges the capacitor (CNRCS) externally connected. When the NRCS terminal reaches 1.3V (Voscp), latch operation is carried out and output voltage is turned OFF.

SCP(BD3500/01/02FVM)

BD3500/01/02FVM has short protection (SCP) activated when output becomes 70% or lower than the set voltage. The time when short protection is activated until latching takes place (T_{SCP}) is determined by the following equation:

When short protection is activated, the NRCS terminal provides $20 \,\mu\text{A}$ (typ.) constant current output (lscp), and charges the capacitor (CNRCS) externally connected. When the NRCS terminal reaches 1.3V (Voscp), latch operation is carried out and output voltage is turned OFF.

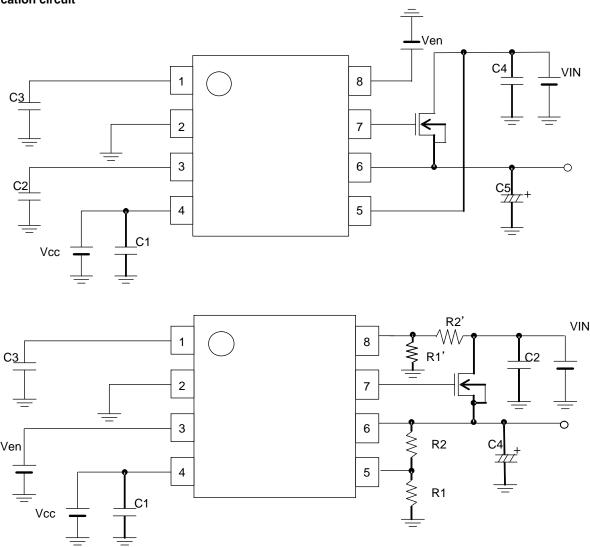
VFB//VS (BD3500FVM/BD3501FVM/BD3502FVM//BD3504FVM)

VFB//VS terminal is a source voltage detection terminal of external N-MOSFET. VFB//VS terminal has the internal discharge circuit activated to lower output voltage when EN becomes a Low level or various protection circuits (TSD, SCP, UVLO) are activated.

٠G

G terminal is a gate drive terminal of external N-MOSFET. Because the output voltage range of G terminal is up to 5V (VCC), it is necessary to use N-MOSFET whose threshold is lower than "5V-VOUT." In addition, by incorporating a RC snubber circuit to the G terminal, phase allowance of loop gain can be increased and the terminal can accommodate ceramic capacitors.

Application circuit

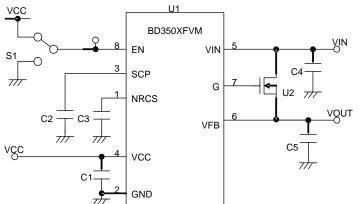


Directions for pattern layout of PCB

- Because a VIN input capacitor causes impedance to drop, mount it as close to the VIN terminal as possible and use thick wiring patterns. In the event that it causes the wire to come in contact with the inner-layer ground plane, use a plurality of through holes.
- Because the NRCS terminal is analog I/O, take care to noise. In particular, high-frequency noise of GND may cause IC maloperation through capacitors. It is recommended to connect GND of NRCS capacitor to IC GND terminal at one point.
- The VFB terminal is an output voltage sense line. Effects of wiring impedance can be ignored by sensing the output voltage from the load side, but increased sense wiring causes VFB to be susceptible to noise, to which care must be taken.
- Because the GND terminal is GND to be used in analog circuit inside BD3501/02/04FVM, connect it at one point to inner-layer GND of substrate by as short pattern as possible. Arrange a bypass capacitor across VCC and GND as close as possible so that a loop can be minimized.
- The G terminal is a terminal for gate drive. If long wiring is inevitable, increase the pattern width and lower impedance.
- Heat generated in the output transistor can be calculated by: (VIN - VOUT) x Io(Max)
 Design heat generation not to exceed the guarantee temperature of transistor.
- Connect the output capacitor with thick short wiring so that the impedance is lowered. Connect capacitor GND to inner-layer GND plane by a plurality of through holes.

● Evaluation Board (BD3500/01/02FVM)

■BD350XFVM Evaluation Board Circuit

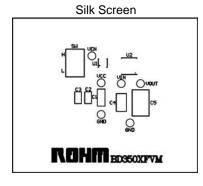


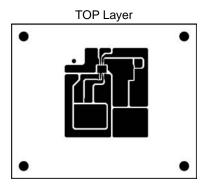
■BD350XFVM Evaluation Board Application Components

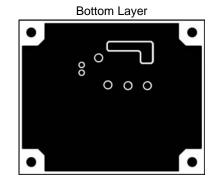
| Part No | Value | Company | Parts Name |
|---------|--------|---------|-----------------|
| U1 | - | ROHM | BD3500/01/02FVM |
| U2 | NMOS | ROHM | RTW060N03 |
| C1 | 1µF | MURATA | GRM18 series |
| C2 | 0.01µF | MURATA | GRM18 series |

| Part No | Value | Company | Parts Name |
|---------|--------|-----------|--------------|
| C3 | 0.01µF | MURATA | GRM18 series |
| C4 | 10µF | MURATA | GRM21 series |
| C5 | 220µF | SANYO,etc | 2R5TPE220MF |

■ BD350XFVM Evaluation Board Layout

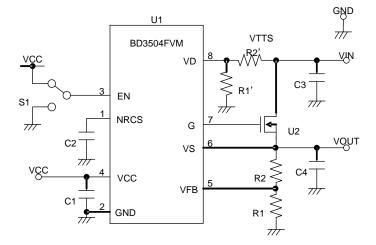






●Evaluation Board (BD3504FVM)

■BD3504FVM Evaluation Board Circuit

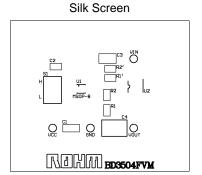


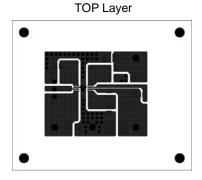
■BD3504FVM Evaluation Board Application Components

| Part No | Value | Company | Parts Name |
|---------|-------|---------|---------------|
| U1 | - | ROHM | BD35304FVM |
| U2 | NMOS | ROHM | RTW060N03 |
| R1 | 3.9K | ROHM | MCR03EZPF3901 |
| R1' | 3.3K | ROHM | MCR03EZPF3301 |
| R2 | 3.9K | ROHM | MCR03EZPF3901 |

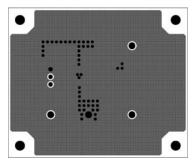
| Part No | Value | Company | Parts Name |
|---------|--------|-----------|---------------|
| R2' | 3.3K | ROHM | MCR03EZPF3301 |
| C1 | 1µF | MURATA | GRM18 series |
| C2 | 0.01µF | MURATA | GRM18 series |
| C3 | 10µF | MURATA | GRM21 series |
| C4 | 220µF | SANYO,etc | 2R5TPE220MF |

■ BD3504FVM Evaluation Board Layout



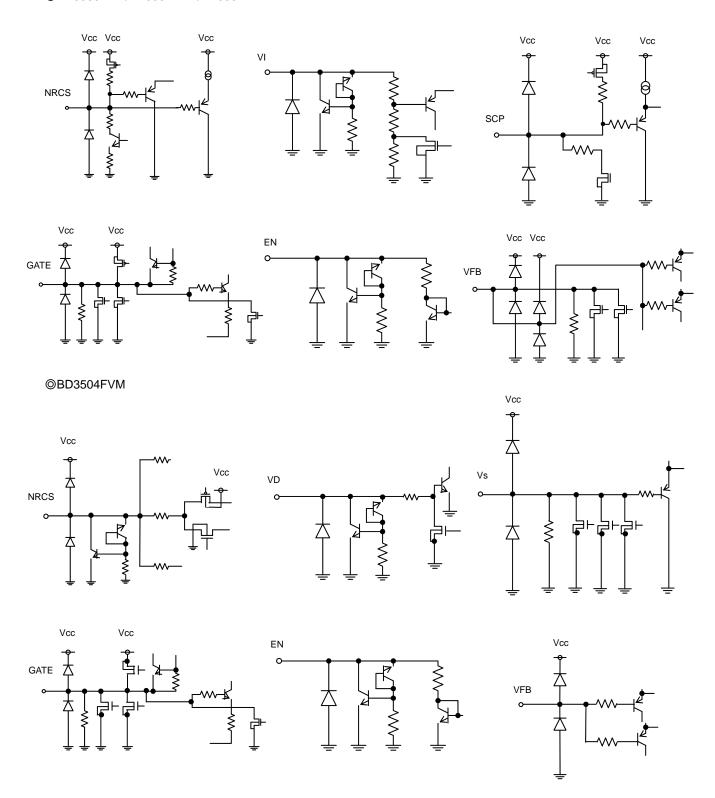


Bottom Layer



●I/O EQUIVALENCE CIRCUIT

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Notes for use

1. Absolute maximum ratings

For the present product, thoroughgoing quality control is carried out, but in the event that applied voltage, working temperature range, and other absolute maximum rating are exceeded, the present product may be destroyed. Because it is unable to identify the short mode, open mode, etc., if any special mode is assumed, which exceeds the absolute maximum rating, physical safety measures are requested to be taken, such as fuses, etc.

2 GND potential

Bring the GND terminal potential to the minimum potential in any operating condition.

3. Thermal design

Consider allowable loss (Pd) under actual working condition and carry out thermal design with sufficient margin provided.

4. Terminal-to-terminal short-circuit and erroneous mounting

When the present IC is mounted to a printed circuit board, take utmost care to direction of IC and displacement. In the event that the IC is mounted erroneously, IC may be destroyed. In the event of short-circuit caused by foreign matter that enters in a clearance between outputs or output and power-GND, the IC may be destroyed.

5. Operation in strong electromagnetic field

The use of the present IC in the strong electromagnetic field may result in maloperation, to which care must be taken.

6. Built-in thermal shutdown protection circuit

The present IC incorporates a thermal shutdown protection circuit (TSD circuit). The working temperature is 175°C (standard value) and has a -15°C (standard value) hysteresis width. When the IC chip temperature rises and the TSD circuit operates, the output terminal is brought to the OFF state. The built-in thermal shutdown protection circuit (TSD circuit) is first and foremost intended for interrupt IC from thermal runaway, and is not intended to protect and warrant the IC. Consequently, never attempt to continuously use the IC after this circuit is activated or to use the circuit with the activation of the circuit premised.

7. Capacitor across output and GND

In the event a large capacitor is connected across output and GND, when Vcc and VIN are short-circuited with 0V or GND for some kind of reasons, current charged in the capacitor flows into the output and may destroy the IC. Use a capacitor smaller than 1000 µF between output and GND.

8. Inspection by set substrate

In the event a capacitor is connected to a pin with low impedance at the time of inspection with a set substrate, there is a fear of applying stress to the IC. Therefore, be sure to discharge electricity for every process. As electrostatic measures, provide grounding in the assembly process, and take utmost care in transportation and storage. Furthermore, when the set substrate is connected to a jig in the inspection process, be sure to turn OFF power supply to connect the jig and be sure to turn OFF power supply to remove the jig.

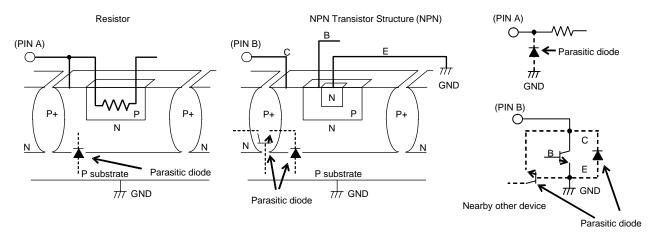
9. IC terminal input

The present IC is a monolithic IC and has a P substrate and P+ isolation between elements.

With this P layer and N layer of each element, PN junction is formed, and when the potential relation is

- •GND>terminal A>terminal B, PN junction works as a diode, and
- •terminal B>GND terminal A, PN junction operates as a parasitic transistor.

The parasitic element is inevitably formed because of the IC construction. The operation of the parasitic element gives rise to mutual interference between circuits and results in malfunction, and eventually, breakdown. Consequently, take utmost care not to use the IC to operate the parasitic element such as applying voltage lower than GND (P substrate) to the input terminal.



10. Output capacitor (C5)

Connect the output capacitor between Vo1, Vo2 terminals and GND terminal without fail in order to stabilize output voltage. The output capacitor has a role to compensate for the phase of loop gain and to reduce output voltage fluctuation when load is rapidly changed. When there is an insufficient capacity value, there is a possibility to cause oscillation, and when the equivalent serial resistance (ESR) of the capacitors is large, output voltage fluctuation is increased when load is rapidly changed. About 220 µF high-performance electrolytic capacitors are recommended, but this greatly depends on the gate capacity of external MOSFET and mutual conductance (gm), temperature and load conditions. In addition, when only ceramic capacitors with low ESR are used, or various capacitors are connected in series, the total phase allowance of loop gain becomes not sufficient, and oscillation may result. Thoroughgoing confirmation at application temperature and under load range conditions is requested.

11. Input capacitor setting method (C1, C4)

The input capacitor plays a part to lower output impedance of a power supply connected to input terminals (Vcc, VIN). When output impedance of this power supply increases, the input voltages (Vcc, VIN) become unstable and there is a possibility of giving rise to oscillation and degraded ripple rejection characteristics. The use of capacitors of about 10 µF with low ESR, which provide less capacity value changes caused by temperature changes, is recommended, but since input capacitor greatly depends on characteristics of the power supply used for input, substrate wiring pattern, and MOSFET gate-drain capacity, thoroughgoing confirmation under the application temperature, load range, and M-MOSFET conditions is requested.

12. NRCS terminal capacitor setting method (C3)

To the present IC, there mounted is a function (Non Rush Current on Start-up: NRCS) to prevent rush current from VIN to load and output capacitor via Vo at the output voltage start-up. When the EN terminal is reset from Hi or UVLO, constant current is allowed to flow from the NRCS terminal. By this current, voltage generated at the NRCS terminal becomes the reference voltage and output voltage is started. In order to stabilize the NRCS set time, it is recommended to use a capacitor (B special) with less capacity value change caused by temperature change.

13. SCP terminal capacitor setting method (C2)

The present IC incorporates a timer-latch type short-circuit protection circuit in order to prevent MOSFET from being destroyed by abnormal current when output terminal is short-circuited (operates at the time of NRCS, too). When the output terminal voltage drops 30% from output setting voltage, IC judges that the output is short-circuited. In such event, constant current begins to flow. When the voltage generated in the SCP terminal reaches 1.3V (Typ) by this current, the gate terminal is brought to the Low level. In order to stabilize the SCP setting time, a capacitor (B special) with less capacity value change caused by temperature changes is recommended. When the SCP function is not used, short-circuit the SCP terminal to the GND terminal. In addition, when the output terminal is short-circuited, the MOSFET gate voltage reaches the Vcc voltage and the large current that meets MOSFET characteristics flows to the output while the timer latch type protection circuit operates. When the current capacity of VIN terminal power supply lacks, the Vin terminal voltage lowers and the UVLO circuit operates, and the latch operation may not be finished. In such event, connect a limiting resistor across drain terminal and VIN terminal of MOSFET.

14. Input terminals (VCC, VIN, EN)

In the present IC, N terminal, VIN terminal, and VCC terminal have an independent construction. In addition, in order to prevent malfunction at the time of low input, the UVLO function is equipped with the VIN terminal and the VCC terminal. They begin to start output voltage when all the terminals reach threshold voltage without depending on the input order of input terminals.

15. Maximum output current (maximum load)

The maximum output current capacity of the power supply which is composed by the use of the present IC depends on the external FET. Consequently, confirm the characteristics of the power required for the set to be used, choose the external FET.

16. Operating ranges

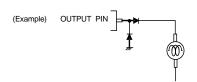
If it is within the operating ranges, certain circuit functions and operations are warranted in the working ambient temperature range. With respect to characteristic values, it is unable to warrant standard values of electric characteristics but there are no sudden variations in characteristic values within these ranges.

17. Allowable loss Pd

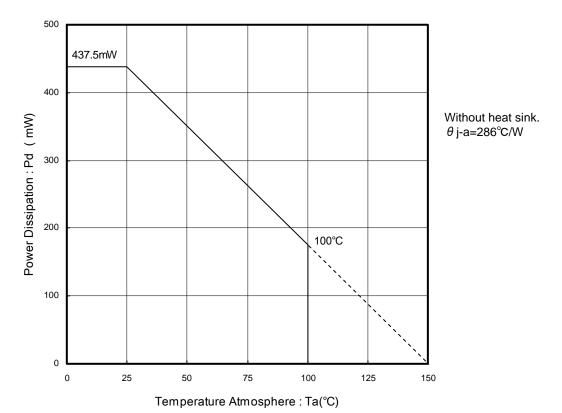
With respect to the allowable loss, the thermal derating characteristics are shown in the Exhibit, which we hope would be used as a good-rule-of-thumb. Should the IC be used in such a manner to exceed the allowable loss, reduction of current capacity due to chip temperature rise, and other degraded properties inherent to the IC would result. You are strongly urged to use the IC within the allowable loss.

- 18. The use in the strong electromagnetic field may sometimes cause malfunction, to which care must be taken.
- 19.In the event that load containing a large inductance component is connected to the output terminal, and generation of back-EMF at the start-up and when output is turned OFF is assumed, it is requested to insert a protection diode.
- 20. We are certain that examples of applied circuit diagrams are recommendable, but you are requested to thoroughly confirm the characteristics before using the IC. In addition, when the IC is used with the external circuit changed, decide the IC with sufficient margin provided.

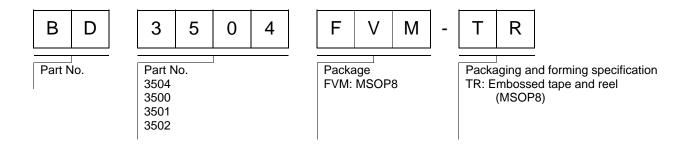
while consideration is being given not only to static characteristics but also variations of external parts and our IC including transient characteristics.



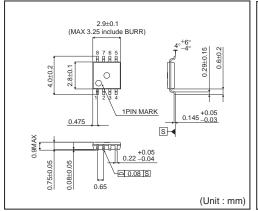
Power Dissipation

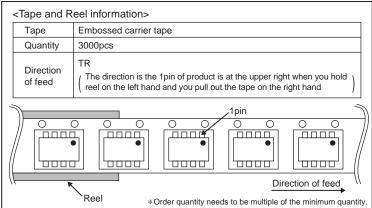


Ordering part number



MSOP8





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